PCN Number:		20230928001.1							PCN Date:		September 28, 2023	
Title:Qualification of RFAB using qualified Process Technology, Die Revision and additional Assembly site/BOM options for select devices												
Customer Contact: Change Management Team Dept: Quality Services												
Propose	ed 1 st Sh	ip Da	te: Dec 29, 2023						e requests pted until:	29, 2023*		
*Sample requests received after Oct 29, 2023 will not be supported.												
Change Type: Image: Stephic Change Type: Image: Assembly Site Image: Stephic Change Type: Image: Change Type: Image: Stephic Change Type:												
	embly Sit							Wafer Bump Material				
	embly Pro			Data Sh			hanga		Wafer Bump Process Wafer Fab Site			
	embly Ma hanical S			tion Dart nur			nange		Wafer Fab I	rial		
					Test Pro				Wafer Fab Process			
	Packing/Shipping/Labeling Test Process Wafer Fab Process PCN Details											
Descrip	tion of C	hang	e:									
									ng the LBC9 (
		-			onal Asse	embly	site (TI M	1alay	vsia) for selec	t de	vices listed	
below in	the prod	uct af	fected sec	ction.								
	C	urre nt	nt Fab Site				Additional Fab Site					
Curre		Pro	ocess		afer meter	-	ditional ab Site		Process		Wafer Diameter	
	DS5	Н	PA07		0 mm		RFAB		LBC9		300 mm	
The die was also changed as a result of the process change. Construction differences are as follows: Group 1 Device:												
			Current				Proposed					
Wire ty	ре		0.9	96mil A	u		0.8mil Cu	I				
Group 2	Dovico											
	Group 2 Device: ASESH						I Malays	ia				
Mount compound				EY1000063			4147858					
				EN2000508								
Mold compound							4211471					
Lead fir	rish		М	atte Sn NiPdAu								
Qual details are provided in the Qual Data Section.												
	for Cha			<u> </u>								
Continuit	y of sup	olv.										
			technoloa	v tren	ds and us	e wiri	na with e	nhar	nced mechan	ical a	and	
-	rical prop			,		•	. 9					
			within ou	Asser	nblv/Test	- produ	uction site	25.				
-			in and sto		1151771000	, prou						
Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):												
None												
Impact	on Envi	ronme	ental Rat	ings:								

RoHS		REACH	Green Status	IE	EC 62474					
No Change		No Change	No Change	No Change						
hanges to produ	uct iden	tification resulting	g from this PCN:							
Fab Site Informa										
Chip SiteChip Site Origin Code (20L)Chip Site Country Code (21L)Chi										
DMOS5		DM5	USA		Dallas					
RFAB		RFB	USA		Richardson					
A A Sembly Site In		ie Rev [2P] A on:		<u> </u>						
Assembly Site Assembly Site Origin (22L) Assembly Country Code (23L) Assembly City										
ASESH ASH CHN Shanghai										
ASESH		ASH	CHN		Shanghai					
TI Malaysia	ipping la	MLA bel (not actual prod	MYS	K	Shanghai (uala Lumpur					
TI Malaysia Sample product sh INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /260C/1 YEAR MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO	G4 SEAL DT 03/29/04 39 1750	MLA bel (not actual prod	MYS uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 31T)LOT: 3959047MLA 4W) TKY (1T) 7523483S12 P) 2P) REV: (V) 0033317 20L) CS0: SHE (21L) CC0:USA 20L) CS0: SHE (21L) CC0:USA 22L) AS0: MLA (23L) ACO: MYS							
TI Malaysia Sample product sh INSTRUMENTS MADE IN: Malaysia 20: MSL 2 /260C/1 YEAR MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO Group 1 Product	G4 SEAL DT 03/29/04 39 1750	MLA bel (not actual prod	MYS uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 31T)LOT: 3959047MLA 4W) TKY (1T) 7523483S12 P) 2P) REV: (V) 0033317 20L) CS0: SHE (21L) CC0:USA 20L) CS0: SHE (21L) CC0:USA 22L) AS0: MLA (23L) ACO: MYS							
TI Malaysia ample product sh TEXAS INSTRUMENTS MADE IN: Malaysia 20: MSL '2 /260C/1 YEAR MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO Group 1 Product LV6004IPWR	G4 SEAL DT 03/29/04 39 1750 Affecte	MLA bel (not actual prod	MYS uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 31T)LOT: 3959047MLA 4W) TKY (1T) 7523483S12 P) 2P) REV: (V) 0033317 20L) CS0: SHE (21L) CC0:USA 20L) CS0: SHE (21L) CC0:USA 22L) AS0: MLA (23L) ACO: MYS							
TI Malaysia Sample product sh INSTRUMENTS MADE IN: Malaysia 20: MSL 2 /260C/1 YEAR MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO Sroup 1 Product LV6004IPWR Sroup 2 Product	G4 SEAL DT 03/29/04 39 1750 Affected Affected	MLA bel (not actual prod	MYS uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 31T) LOT: 3959047MLA 4W) TKY (1T) 7523483SI2 P) 2P) REV: (V) 0033317 20L) CS0: SHE (21L) CC0:USA 22L) AS0: MLA (23L) AC0: MYS BOM		Kuala Lumpur					
TI Malaysia Sample product sh TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /260C/1 YEAR MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO Group 1 Product IV6004IPWR Group 2 Product LM2902LVIPWR	SEAL DT 03/29/04 39 1750 Affecte Affecte	MLA bel (not actual prod	MYS uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 31T)LOT: 3959047MLA 4W) TKY (1T) 7523483SI2 P) 2P) REV: (V) 0033317 20L) CS0: SHE (21L) CC0:USA 22L) AS0: MLA (23L) ACO: MYS BOM TLV9054IPWR T		Kuala Lumpur					
TI Malaysia Sample product sh INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /260C/1 YEAR MSL 1 /235C/UNLIM OPT: ITEM: LBL: 5A (L)TO Group 1 Product ILV6004IPWR Group 2 Product	G4 SEAL DT 03/29/04 39 1750 Affected MC SN	MLA bel (not actual prod	MYS uct label) 1P) SN74LS07NSR (Q) 2000 (D) 0336 31T) LOT: 3959047MLA 4W) TKY (1T) 7523483SI2 P) 2P) REV: (V) 0033317 20L) CS0: SHE (21L) CC0:USA 22L) AS0: MLA (23L) AC0: MYS BOM		Kuala Lumpur					

Group 1 Qualification Report

Approve Date 13-JANUARY -2023

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

	Data Displayed as: Number of lots / Total sample size / Total failed									
Туре	#	Test Name	Condition	Duration	Qual Device: <u>TLV9004IPWR</u>	QBS Reference: TLV7031QDCKRQ1	QBS Reference: <u>SN74HCS74QPWRQ1</u>	QBS Reference: OPA4991QPWRQ1	QBS Reference: TLV9004QPWRQ1	
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	1/77/0	-	
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	2/154/0	-	
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	3/231/0	-	1/77/0	
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	3/231/0	3/231/0	1/77/0	
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-	-	
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0	1/77/0	
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	3/231/0	3/135/0	3/135/0	-	
HTOL	В1	Life Test	125C	1000 Hours	-	3/231/0	3/231/0	-	-	
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	3/2400/0	-	-	
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	1/15/0	1/15/0	-	-	
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	1/15/0	1/15/0	-	-	
PD	C4	Physical Dimensions	Cpk>1.67	-	-	3/30/0	3/30/0	1/10/0	-	
ESD	E2	ESD CDM	-	500 Volts	-	1/3/0	1/3/0	-	-	
ESD	E2	ESD HBM	-	2000 Volts	-	1/3/0	1/3/0	-	-	
LU	E4	Latch-Up	Per JESD78	-	-	1/6/0	1/6/0	3/18/0	1/6/0	
CHAR	E5	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-	3/90/0	3/90/0	3/90/0	3/90/0	

QBS: Qual By Similarity

Qual Device TLV9004IPWR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

Group 2 Qualification Report Approve Date 26-JULY -2023

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

			Data Dispi	ayeu as		511013 / 101	al sample size /			
Туре		Test Name	Condition	Duration	Qual Device: <u>TLV9064IPWR</u>	Qual Device: <u>TLV9054IPWR</u>	QBS Reference: SN74HCS74QPWRQ1	QBS Reference: <u>TLV9064QDRQ1</u>	QBS Reference: <u>TLV9054IDR</u>	QBS Reference: <u>OPA4991QPWRQ1</u>
HAST	A2	Biased HAST	110C/85%RH	264 Hours	-	-	-	-	-	1/77/0
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	-	-	-	3/231/0	-
UHAST	A3	Autoclave	121C/15psig	96 Hours	0/0/0	0/0/0	0/0/0	0/0/0	0/0/0	3/231/0
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	-		3/231/0	3/231/0	-
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-		-	3/231/0	2/154/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	3/135/0	3/135/0	-	1/45/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	-	-	-	3/231/0	-
HTOL	B1	Life Test	125C	1000 Hours	-	-	3/231/0	3/231/0	1/77/0	-
HTOL	B1	Life Test	150C	300 Hours	-	-	-	-	-	3/231/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	-	3/2400/0	3/2400/0	-	-
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	1/15/0	1/15/0	-	-
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	1/15/0	1/15/0	-	-
PD	C4	Physical Dimensions	Cpk>1.67	-	-	-	3/30/0	3/30/0	-	1/10/0
ESD	E2	ESD CDM	-	1500 Volts	-	-	-	-	-	1/3/0
ESD	E2	ESD CDM	-	250 Volts	-	-		-	1/3/0	-
ESD	E2	ESD CDM	-	500 Volts	-	-	1/3/0	1/3/0	-	-
ESD	E2	ESD HBM	-	1000 Volts	-	-	-	-	1/3/0	-
ESD	E2	ESD HBM	-	2000 Volts		-	1/3/0	1/3/0	-	-
ESD	E2	ESD HBM	-	4000 Volts	-	-		-	-	1/3/0
LU	E4	Latch-Up	Per JESD78	-	-	-	1/6/0	1/6/0	1/6/0	3/18/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	-	-	-	-	1/30/0	-
CHAR	E5	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-	-	3/90/0	3/90/0	-	3/90/0

QBS: Qual By Similarity

Qual Device TLV9064IPWR is qualified at MSL1 260C Qual Device TLV9054IPWR is qualified at MSL1 260C

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7 eV : 150C/1k Hours, and 170C/420 Hours

The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

For questions regarding this notice, e-mails can be sent to Change Management team or your local Field Sales Representative.

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